EVERLIGHT ELECTRONICS CO., LTD.

3mm Silicon PIN Photodiode

MODEL NO : PD204-6B

Features :

- Fast response time
- High photo sensitivity
- Small junction capacitance

Description :

PD204-6B is a high speed and high sensitive PIN photodiode in a standard 3Φ plastic package. The device is spectrally matched to infrared emitting diode.

Applications :

- High speed photo detector
- Camera
- Optoelectronic switch
- VCRs ,Video camera
- Floppy disk drive

PART NO.	CHIP MATERIAL	LENS COLOR
PD	Silicon	Black

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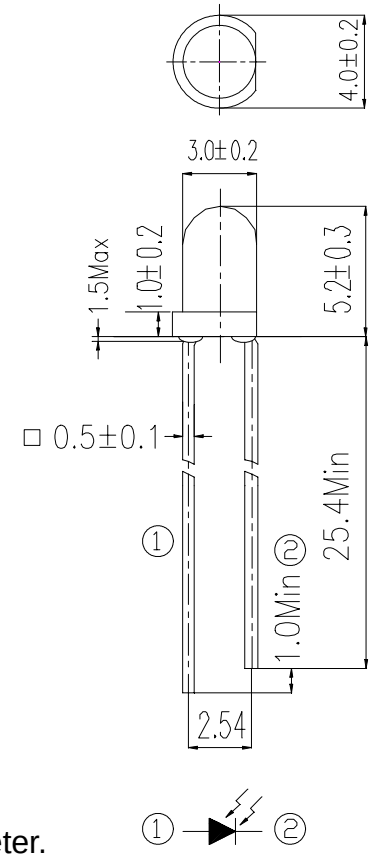
Package Dimensions :



Notes :

1.All dimensions are in millimeter.

2.Protruded resin under flange 1.5 mm Max.

3.Lead spacing is measured where the lead emerge from the package.

4.Lens color：Black.

5.Above specification may be changed without notice. EVERLIGHT will reserve authority on material change for above specification.

6.These specification sheets include materials protected under copyright of EVERLIGHT corporation . Please don’t reproduce or cause anyone to reproduce them without EVERLIGHT’s consent.

7.When using this product , please observe the absolute maximum ratings and the instructions for use outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.

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■ Absolute Maximum Ratings at T_A = 25℃

Parameter	Symbol	Rating	Unit	Notice
Reverse Voltage	V_R	32	V	
Power Dissipation	Pd	150	mW	
Lead Soldering Temperature	Tsol	260	℃	4mm from mold body less than 5 seconds
Operating Temperature	Topr	-25 ~ +85	℃	
Storage Temperature	Tstg	-40 ~ +85	℃	

■ Electronic Optical Characteristics :

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Rang of Spectral Bandwidth	$\lambda_{0.5}$	----	840-1200	----	nm	----------
Wavelength of Peak Sensitivity	λ_P	----	980	----	nm	----------
Open-Circuit Voltage	Voc	----	0.42	----	V	Ee=5m W/c ㎡ λp=940nm
Short-Circuit Current	Isc	----	15	----	μA	
Reverse Light Current	I_L	----	15	----	μA	Ee=5m W/c ㎡ λp=940nm V_R=5V
Dark Current	Id	----	----	10	nA	Ee=0m W/c ㎡ V_R=10V
Reverse Breakdown Voltage	BV_R	32	170	----	V	Ee=0m W/c ㎡ I_R=100μA
Total Capacitance	Ct	----	5	----	pF	Ee=0m W/c ㎡ V_R=5V,f=1MHz
Rise/Fall Time	t_r/t_f	----	6/6	----	nS	V_R=10V R_L=1KΩ

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■ Typical Electrical/Optical/Characteristics Curves

Fig. 1 Power Dissipation vs. Ambient Temperature

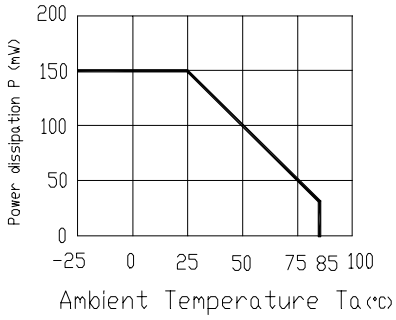


Fig. 2 Spectral Sensitivity

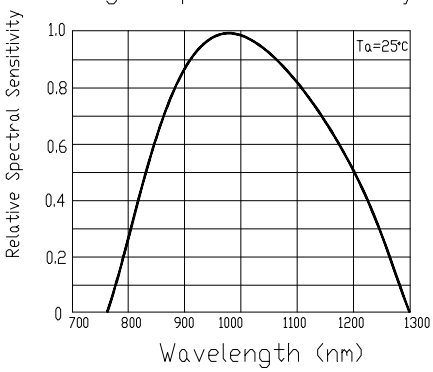


Fig.3 Dark Current vs. Ambient Temperature

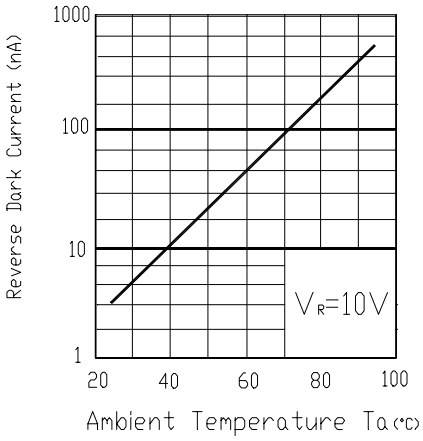


Fig.4 Reverse Light Current vs.Ee

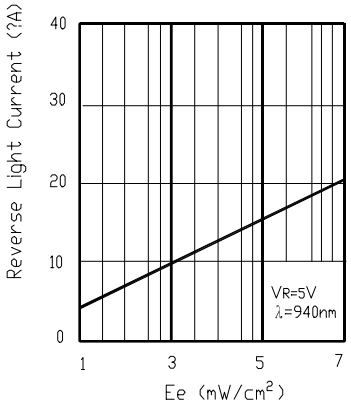


Fig.5 Terminal Capacitance vs. Revere Voltage

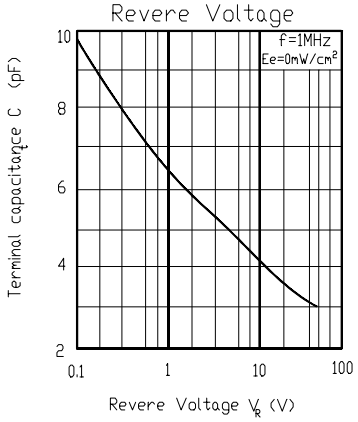
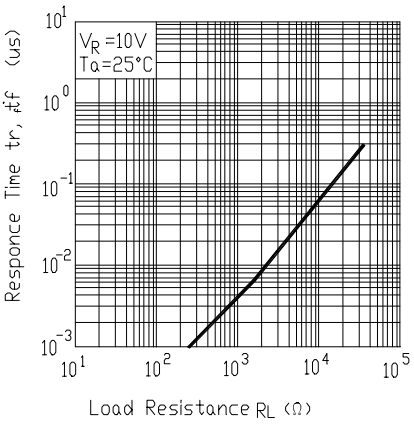


Fig.6 Responce Time vs. Load Resistance



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■ Reliability Test Item And Condition

The reliability of products shall be satisfied with items listed below.
Confidence level:90%
LTPD:10%

NO.	Item	Test Conditions	Test Hours/ Cycle	Sample Size	Failure Judgement Criteria	Ac/Re
1	**Solder Heat**	TEMP : 260℃ ± 5 ℃	5 sec	22 PCs	$I_L \leqq L \times 0.8$ L :Lower specification limit	0/1
2	**Temperature Cycle**	H : +85℃ 30 min 5 min L : -55℃ 30 min	50 cycle	22 PCs		0/1
3	**Thermal Shock**	H : +100℃ 5 min 10 sec L : -10℃ 5 min	50 cycle	22 PCs		0/1
4	**High Temperature Storage**	TEMP. : +100℃	1000 hrs	22 PCs		0/1
5	**Low Temperature Storage**	TEMP. : -55℃	1000 hrs	22 PCs		0/1
6	**DC Operating Life**	V_R=5V	1000 hrs	22 PCs		0/1
7	**High Temperature / High Humidity**	85℃ / 85% R.H.	1000 hrs	22 PCs		0/1

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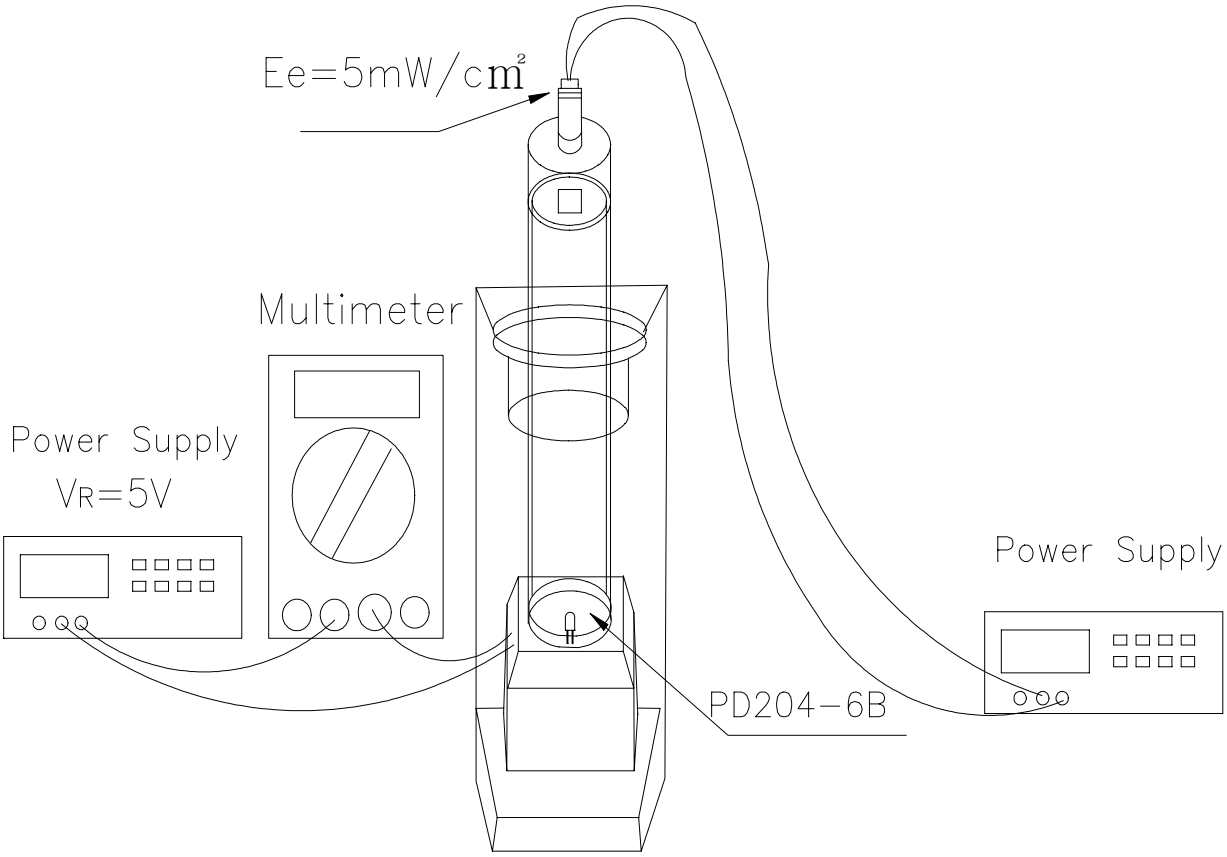
■ Test Method For Reverse Light Current

Condition: Ee=5mW/cm², V_R=5V

Test Item: Reverse Light Current

Unit : μA



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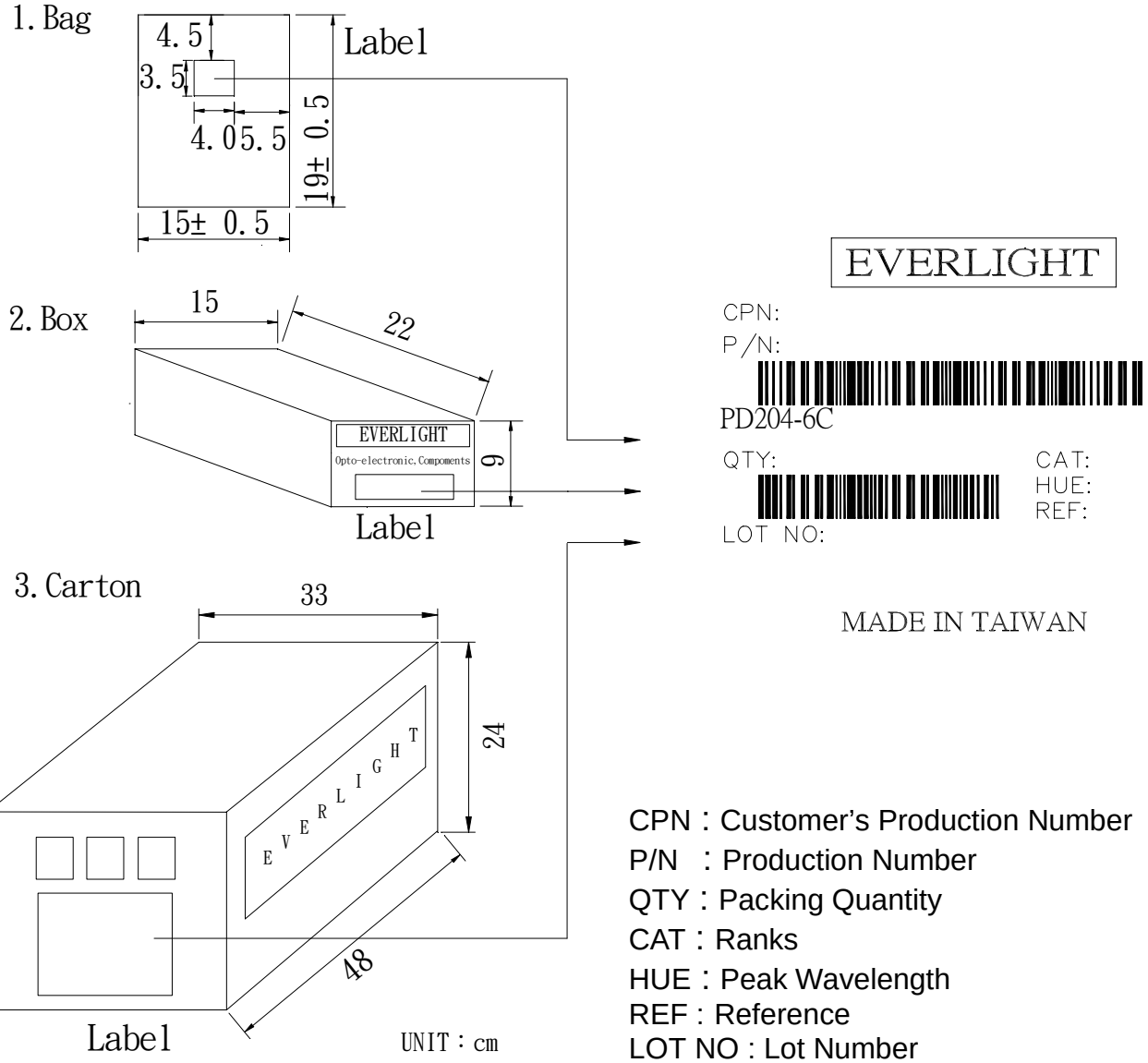
■ Packing Specifications



CPN：Customer's Production Number
P/N ：Production Number
QTY：Packing Quantity
CAT：Ranks
HUE：Peak Wavelength
REF : Reference
LOT NO : Lot Number
MADE IN TAIWAN：Production place

■ Packing Quantity Specification

1. 1000 Pcs/1Bag，4 Bags/1Box
2. 10 Boxes/1Carton